Accumulative Magnetic Switching of Ultrahigh-Density Recording Media by Circularly Polarized Light


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Accumulative magnetic switching of ultra-high-density recording media by circularly polarized light

1Y.K. Takahashi*, 2R. Medapalli, 1S. Kasai, 1J. Wang, 1K. Ishioka, 3S.H. Wee, 4,5O. Hellwig, 1K. Hono and 2E.E. Fullerton

1 Magnetic Materials Unit, National Institute for Materials Science, 1-2-1 Sengen, Tsukuba 305-0047, Japan
2 Center for Memory and Recording Research, University of California San Diego, 9500 Gilman Drive, La Jolla, CA 92093-0401, USA
3 San Jose Research Center, HGST a Western Digital company, 3403 Yerba Buena Road, San Jose, CA 95135, USA
4Institut fur Ionenstrahlphysik und Materialforschung, Helmholtz-Zentrum Dresden-Rossendorf, Bautzner Landstr. 400, D-01328 Dresden, Germany
5Institut fur Physik, Technische Universitat Chemnitz, D-09126 Chemnitz, Germany

Corresponding author; Y.K. Takahashi

Magnetic Materials Unit, National Institute for Materials Science, 1-2-1 Sengen, Tsukuba 305-0047, Japan

e-mail: takahashi.yukiko@nims.go.jp
ABSTRACT

Magnetization control of ferromagnetic materials only by circularly polarized light has received increasing attention both as a fundamental probe of the interactions of light and magnetism but also for future high-density magnetic recording technologies. Here we show that for granular FePt films, designed for ultrahigh-density magnetic recording, the optical magnetic switching by circularly polarized light is an accumulative effect from multiple optical pulses. The measured results can be reproduced by a simple statistical model where the probability of switching a grain depends on the helicity of the optical pulses. We further show the deterministic switching of high anisotropy materials by the combination of circularly polarized light and modest external magnetic fields, thus revealing a pathway towards technological implementation.
I. INTRODUCTION

Deterministic control of magnetization by light, often referred to as all-optical switching (AOS), is an attractive recording method for magnetic nanotechnologies because magnetization control becomes possible without the need of an external magnetic field\textsuperscript{1-5} and therefore incorporates the potential for ultra-fast magnetization switching up to 1000 times faster than that by magnetic fields while using lower energies\textsuperscript{6}. The first demonstration of the magnetization switching by light was in ferrimagnetic GdFeCo film which is a magneto-optical material\textsuperscript{1} where the Gd and FeCo spin sub-lattices are antiferromagnetically exchange coupled. While several mechanisms for the ultrafast magnetization switching of GdFeCo have been explored\textsuperscript{7-9}, the current understanding for AOS in GdFeCo is that the ultrafast laser excitation demagnetizes the two sublattices at different time-scales\textsuperscript{6} resulting in a transient ferromagnetic state where the Gd and FeCo sublattices are parallel. At later times, as the Gd moment reemerges in the antiparallel orientation due to the exchange interaction, the sublattice moments end up in the opposite direction as compared to the initial state. The deterministic helicity dependent switching observed in the experiments results from helicity dependent absorption (dichroism) which favors one magnetic configuration over the other for a narrow range of fluence\textsuperscript{10}.

It was believed that AOS occurs only in ferrimagnetic materials including synthetic structures\textsuperscript{1-4} since the mechanism determined for GdFeCo films required antiparallel exchange of two sublattice systems. However, Lambert et al. reported the deterministic optical control of
magnetization in ferromagnets including Co-based multilayer thin films and FePtAg-C granular thin film materials. Therefore the potential mechanisms for AOS in ferromagnetic materials must be reexamined. In addition, the observation of AOS in granular FePt-based films being developed for heat-assisted magnetic recording (HAMR) directly impacts the magnetic recording community, since it provides a potential solution to the so-called “trilemma problem” in high-density hard disk drives (HDDs) beyond 1 Tbit/in\(^2\). Here, to probe both the mechanisms of optical reversal and its potential for novel technologies, we report the observation of accumulative magnetic switching from multiple circularly polarized light pulses on FePt-C granular HAMR media.

II. EXPERIMENT

The FePt-30vol%\(\text{C}\) (hereafter, FePt-C) granular film was deposited by co-sputtering of FePt and C targets on a MgO(001) single-crystal substrate by DC magnetron sputtering under 0.48 Pa Ar pressure at 600°C. After the deposition of 10-nm-thick FePt-C, the sample was cooled down to RT and 10-nm-thick C was deposited as a capping layer. In this work, we used a compositionally graded sputtering method to obtain the columnar FePt grains. In this process, the C composition gradually changed during the deposition, which gives the nice FePt grain isolation shown in Fig. 2(a). To investigate the morphological effect on AOS, a 10-nm-thick FePt continuous film was prepared by the sputtering from an FePt alloy target under 0.48 Pa Ar pressure at 400°C. A 10-nm-thick C capping was deposited on the FePt continuous film at RT. We further studied composite FePt-C/FePt
structure where the FePt-C granular layer deposited at 600°C as described above and then a FePt layer was deposited at 400°C and therefore the degree of L1₀ ordering is lower than that of the FePt-C granular layer. The detailed description of the film processing conditions and their magnetic characteristics were reported elsewhere¹⁶.

Hall cross structures were used for the measurement of the magnetization change by the light exposure and/or applied magnetic fields. The Hall resistance corresponds to the average out-of-plane component in the magnetization of the FePt grains within the Hall-cross area via the anomalous Hall effect (AHE). The Hall crosses were fabricated directly from the films by photo-lithography using a lift-off process and a subsequent Ar ion-milling step. The width of the Hall cross is about 20 μm. The sample microstructure and magnetic properties were measured by transmission electron microscopy (TEM) and vibrating sample magnetometer (VSM), respectively. The room-temperature magnetic hysteresis of the Hall cross area was determined by measuring the Hall resistance as a function of applied field. This measurement further allowed us to normalize the Hall resistance value in optical experiments.

Figure 1 shows the optical setup for this experiment. A light-emitting diode (LED) with 590-nm wavelength was used for the observation of the magnetic domains of the sample in a Faraday microscope. An output of a regenerative amplifier with center wavelength of 800 nm, pulse duration of ~150 fs and a repetition rate of 1 kHz was used to excite the magnetization state of the sample. The excitation pulses were focused into a spot of 30-50 μm diameter on the sample, which covered
the whole region of the Hall cross. Two experiments were performed. In the first, the laser spot was slowly swept over the films or Hall crosses as done in Lambert et al.\textsuperscript{5} and the optical images or Hall voltage was subsequently measured to quantify the magnetization change. In the second experiment, the laser spot was fixed to the Hall-cross area. After exposing the sample to several optical pulses, the Hall voltage was measured and this process was repeated. The number of pulses exposed on the sample was controlled by a mechanical shutter. We estimated the laser-induced change in the magnetization from the differences in Hall resistance before and after the exposure. We applied this method to obtain the results discussed throughout this paper.

III. RESULTS

A. Microstructure and magnetic properties of FePt continuous and granular films

Figure 2(a) shows a plan-view TEM bright-field image of the FePt-C films along with the corresponding nanobeam diffraction (ND) pattern and histogram of the grain sizes. The dark contrast areas are the FePt grains and the bright contrast area is the carbon(C) segregant. The average grain size is ~11.9 nm and these grains are distributed within an amorphous C matrix. The ND pattern indicates that all of the FePt grains have strong (001) texture because of the epitaxial growth on the MgO(001) single-crystal substrate. Figure 2(b) shows a cross sectional TEM image of the FePt-C granular film. The aspect ratio of the FePt grains is roughly 1. Figure 2(c) shows the magnetization curves of FePt-C granular film. Red and blue symbols correspond to the magnetization with the
applied magnetic field perpendicular and parallel to the film surface, respectively. The film shows strong perpendicular magnetic anisotropy with a saturation field of 7 T for the in-plane applied field and high coercive field ($\mu_0H_c$) of 4 T when the field applied normal to the surface due to the strong (001) texture and highly L1_0 ordered FePt grains.

Figure 2(d) shows the plan-view TEM bright field image and ND pattern of the FePt continuous film. The film shows a continuous microstructure and epitaxial growth on the MgO(001) substrate. In contrast to the magnetic properties of the granular film shown in Fig. 2(c), the $\mu_0H_c$ of the FePt continuous film is only 0.17 T due to the small number of pinning sites for domain wall motion. Although the $\mu_0H_c$ is small, the anisotropy field is about 4 T. The smaller anisotropy field in FePt continuous films is attributed to the low degree of L1_0 ordering (S=0.51) caused by lower deposition temperature of 400°C.

B. All-optical switching (AOS) in FePt-C granular media

Figures 3(a) and (b) show the magneto-optical images at remanence of an initially demagnetized sample (a) and a sample after saturation at 7 T (b) for FePt-C granular film after scanning it with both right circularly polarized (RCP) and left circularly polarized (LCP) light pulses. The fluence of the laser was 35.7 mJ/cm² and 48.1 mJ/cm² for (a) and (b), respectively. As was reported in Ref. 5 the optical pulses induce a net magnetization in the FePt granular media and the sign of the magnetization is determined by the helicity of the light. To quantify the optically-induced
magnetization, Hall resistance changes are normalized by the field-dependent hysteresis loop, which reveals $\sim 2.75 \, \Omega$ change in Hall resistance between negative and positive saturation in Fig. 3(c). We first sweep the laser over the Hall cross in a similar way as shown in Fig. 3(a) and measure an induced magnetization. It is roughly 66% of the saturation magnetization as shown in Fig. 3(c). The fluence of the laser was 35.7 mJ/cm$^2$. We then fixed the laser over the Hall cross region to measure the evolution of the magnetization to a series of ultrafast laser pulses. We initially used 40 optical pulses of 101.9 mJ/cm$^2$ for the first three exposures, and then, increased to 80 pulses for the next five to six exposures. In Figs. 3(d) and 3(e), the dashed line shows the change of the number of pulse for each exposure. The Hall resistance was measured after each sequence and then plotted as a function of the integrated number of pulses. The initial state is remanence after applying saturating magnetic fields of -7 T (Fig. 3(d)) and 7 T (Fig. 3(e)). Figure 3(d) shows the normalized Hall resistance change after the exposure to RCP, linearly polarized and LCP optical pulses. For RCP light, the normalized magnetization gradually decreases to zero, then reverses and saturates at about -0.5. This indicates that $\sim 3/4$ of the FePt grains switch to the opposite direction. On the other hand, the exposure to LCP light decreases the magnetization to about half of the initial value, corresponding to the switching of $\sim 1/4$ of the FePt grains. For exposure to linearly polarized light, the normalized Hall resistance gradually approaches zero indicating that half of the grains have switched. In the case of the opposite initial state (negative saturation) shown in Fig. 3(e), RCP, LCP and linearly polarized light exposures result in the same final normalized magnetization of -0.5, 0.5 and zero, respectively. The results
suggest that the magnetization state after exposure to polarized light only depends on the helicity of the light and is independent of the initial magnetization state. More importantly, the results show that the final state is reached only after ~500 pulses are applied for this specific laser power.

Figure 4 shows the change of the normalized Hall resistance in a FePt-C film measured with increasing pulse number. The sample is exposed between measurements at the laser powers of (a) 79.6 mJ/cm² and (b) 107.5 mJ/cm². The initial state is spin-up for all FePt grains and the sample was exposed to RCP light. At the lower power of 79.6 mJ/cm² shown in Fig. 4(a), exposing the sample to a series of 20 optical pulses does not significantly perturb the system. By increasing the number of pulses between measurements of the Hall voltage, the magnetization decreases. However, we do not observe a net switching into the opposite direction. This indicates that the small laser power does not provide sufficient instantaneous heat for a significant magnetization switching to occur, but that only accumulated heat from many optical pulses at 1 kHz repetition rate can slowly thermally demagnetize the sample. At higher power of 107.5 mJ/cm² shown in Fig. 4(b), the Hall resistance decreases much faster after the first laser exposure. In sets of 20 and 40 pulses, the Hall resistance decreases significantly by illumination of RCP light, however, the overall magnetization direction of the film still remains positive, just as for the initial state. When using sets of 60 and 80 pulses, the normalized Hall resistance then changes sign to -0.5. However, for sets of 160 pulses at a time, the normalized Hall resistance decreases only to -0.4, which may be due to excess accumulated heat in the sample from the longer sequence of pulses. Further increase of the pulse number such as 1000
pulses results in a non-monotonous and non-reproducible behavior after the exposure of 10000 pulses (10 sequences), the AHE vs. magnetic field curve was no longer the same as that before the laser exposure. It means the Hall cross received the destructive damage by the 1000 pulse sequence. Independent of laser conditions, the maximum optical induced magnetization switching using a fixed laser beam is roughly half the saturation magnetization and is an accumulative effect using multiple optical pulses.

C. Morphological effect on AOS

To probe the microstructural effect on the magnetization switching, we compare the Hall resistance change between granular FePt-C and a continuous 10-nm-thick FePt films. Figure 5 shows the normalized Hall resistance change as a function of the fluence of RCP optical pulses in FePt-C granular and FePt continuous films. The normalized Hall resistance decreases in both of the samples. However, in contrast to the granular FePt film, the continuous film simply demagnetizes with further increase of the RCP light pulse fluence, which is consistent with the thermal demagnetization and the formation of domains as seen in thick Co/Pt multilayer films driven by strong dipolar energies. In the granular film, the dipole energy is much smaller than that of the continuous film and the magnetization reversal cannot progress by domain wall motion because of the break in magnetic exchange between the magnetic grains. When the fluence is higher than 107.5 mJ/cm², the FePt-C granular films received destructive damage because of the poor thermal conductivity. We have
further observed a continuous transitional behavior between these two extreme behaviors in intermediate exchange composite granular/continuous films as shown in the next section.

D. AOS in exchange-coupled composite (ECC) media

Exchange-coupled composite (ECC) media was proposed in order to ameliorate the so-called “trilemma problem” in magnetic recording\textsuperscript{13,14,17}. By putting the magnetically soft layer on top of the CoCrPt or FePt granular layer, the switching field can be effectively reduced while maintaining the energy barrier for the magnetization rotation\textsuperscript{13,14,18,19}. Wang \textit{et al.} reported a significant reduction of switching field in FePt-C granular media by adding a continuous FePt layer to the high anisotropy granular layer\textsuperscript{16}, which we use for AOS experiment here. Figure 6 shows the schematic view of the film stack, magnetization curves and microstructures of the ECC media with various FePt layer thicknesses. With increasing the FePt layer thickness from 0 to 15 nm, the morphology of the capping layer is changed from partially granular to continuous and the perpendicular $\mu_0H_c$ reduces from 4.9 T to 1.4 T.

Figure 7 shows the change of the normalized Hall resistance of the initially demagnetized films after exposure to RCP light across the Hall cross at a fluence of 24.5 mJ/cm\textsuperscript{2}. The magnetization switching ratio decreases with increasing thickness of the FePt layer. The inset shows the Hall resistance changes by circular polarized light in FePt-C/FePt(15nm) ECC media. The magnetization switches depending on the helicity of the light and shows zero when linearly polarized light was used.
The resistance change by the light illumination is reproducible. However, the magnetization switching ratio is very small, only 1.5%. These results also support that the large dipole energy and domain formation only allows for a small magnetization switching in the continuous film.

E. Deterministic switching in FePt-C granular media

To achieve deterministic switching, we additionally applied a small external magnetic field, while applying 80 optical pulses at a fluence of 107.5 mJ/cm$^2$ for each sequence. Figure 8(a) shows the normalized Hall resistance change after exposure to linear polarized laser under an external magnetic field of 0.051 T. Regardless of the polarity of the external magnetic field, the magnetization of the FePt-C granular film remains close to the demagnetized state. When the external magnetic field is increased to ~0.2 T as shown in Fig. 8(b), the magnetization changes depend on the external magnetic field polarity, but only about half of the total magnetization can be switched by a 0.2-T field. This is consistent with earlier studies observing the combined effect of optical pulse and applied magnetic fields in FePt media where 0.5 T field is required to saturate the magnetization. In the HAMR process, the applied magnetic field is not needed to overcome the coercive field but overcome thermal activation of the nanoparticles near $T_C$. However, by the combination of the circularly polarized light and an external magnetic field of 0.2 T, a magnetization reversal >90% of the saturation magnetization can be achieved as shown in Fig. 8(c) and thus the use of circular polarized light greatly lower the applied field and increase the effective magnetic field gradient for
IV. DISCUSSION

To understand the switching mechanism by circularly polarized light in FePt granular film, the data shown in Figs. 3(d) and (e) were fitted by a simple accumulative switching model where we treat the FePt grains as having two magnetic states, spin-up and spin-down states, because of its high magnetic anisotropy and small grain size. The total number of FePt grains $N$ is expressed by the summation of spin-up grains $N^\uparrow$ and spin-down grains $N^\downarrow$ and the normalized magnetization is given by $(N^\uparrow - N^\downarrow)/(N^\uparrow + N^\downarrow)$. We assume that with each optical pulse there is a switching probability from spin-up to spin-down state given by $P_1$ and from spin-down to spin-up by $P_2$. The number of FePt grains with spin-up and spin-down states after the $n^{th}$ pulse can be expressed by the state after the $(n-1)$ pulse following:

$$N^n_{\uparrow} = N^{n-1}_{\uparrow} (1 - P_1) + N^{n-1}_{\downarrow} P_2 \quad \text{and} \quad N^n_{\downarrow} = N - N^n_{\uparrow} \quad (1)$$

The fitted lines to Eq. (1) are shown in Fig. 3(d) and (e) using the same switching probabilities for RCP, LCP and linearly polarized light exposure: $(P_1, P_2) = (0.0048, 0.0016), (0.0016, 0.0048)$ and $(0.0032, 0.0032)$, respectively. The calculations assume $N^{n=0}_{\uparrow} = N$ for Fig. 3(d) and $N^{n=0}_{\uparrow} = 0$ for Fig. 3(e). The fits describe the data well and suggest that the switching probability by a single pulse is very small, less than 1%. However, accumulating the small switching probabilities results in a continuous change in the magnetization until the final equilibrium state where $N_{\uparrow} P_1 = N_{\downarrow} P_2$ (a final
state normalized magnetization of \( \frac{(P_2-P_1)}{(P_2+P_1)} \) is reached. This final state is independent of the initial state of the magnetization as seen experimentally. The switching probability for the linearly polarized light is given by \( \sim \frac{(P_1+P_2)}{2} \), because the linearly polarized light is composed of a combination of equal amount of LCP and RCP light. The switching probability \( P \) could be a function of the total magnetization, temperature and specific heat as suggested by the results in Fig. 4. However, to keep the discussion part simple, we assume that the \( P_1 \) and \( P_2 \) remain the same or they change by a small amount after every next pump pulse excitation.

What is the origin for different switching probability of \( P_1 \) and \( P_2 \) for circularly polarized light pulses? The fact that linear light leads to demagnetization of the sample suggest that heating of the FePt grains by the femto-second laser exposure is sufficient to cause thermally activated reversal. The circularly polarized light then breaks the symmetry of the system favoring one magnetic state over the other and leading to an imbalance in \( P_1 \) and \( P_2 \). This symmetry breaking could result from a direct interaction between the light and the magnetic systems such as the inverse Faraday field that prefers one direction over the other\(^{21} \). The difference in \( P_1 \) and \( P_2 \) could also arise from differential absorption for RCP and LCP (\textit{i.e.} magnetic circular dichroism) that will result in a slight difference in temperature for one set of grains compared to the other.\(^{10} \) We have roughly estimated the difference in temperature needed during the optical excitation to explain the difference in switching probability using a simple Arrhenius-Néel model for single domain particles where the time-dependence of magnetization of an ensemble of particles versus time \( t \) is given by:
\[ M(t) = M(t = 0) \exp \left( -\frac{t}{\tau} \right) \]  \hspace{1cm} (2)

where \( \tau \) is the characteristic time for thermal switching. In zero external field, \( \tau \) is given by:

\[ \tau = \tau_0 \exp \left( \frac{K_u V}{k_B T} \right) \]  \hspace{1cm} (3)

where \( K_u V \) is the magnetic energy of the particle that is the product of the magnetic anisotropy \( K_u \) and the particle volume \( V \) and \( \tau_0 \) is the attempt time for thermal activation (typically 0.1 ns for high-anisotropy magnetic systems). Assuming that \( M(t)/M(t=0) \) equals \( 1-P_1 \) for RCP light and \( 1-P_2 \) for LCP, then one can estimate \( \tau_{\text{LCP}}/\tau_{\text{RCP}} \) assuming the time \( t \) is the same for RCP and LCP excitation by:

\[ \frac{\tau_{\text{LCP}}}{\tau_{\text{RCP}}} = \frac{\ln (1-P_2)}{\ln (1-P_2)} \]  \hspace{1cm} (4)

Combing Eqs. (2) and (3), we can estimate the difference in \( K_u V/k_B T \) between RCP and LCP excitations, which is given by

\[ \left( \frac{K_u V}{k_B T} \right)_{\text{LCP}} - \left( \frac{K_u V}{k_B T} \right)_{\text{RCP}} = \ln \left( \frac{\tau_{\text{LCP}}}{\tau_{\text{RCP}}} \right) . \]  \hspace{1cm} (5)

For \( P_1 = 0.0048 \) and \( P_2 = 0.0016 \), then Eq. (4) gives \( \tau_{\text{LCP}}/\tau_{\text{RCP}} = 3.005 \) and the corresponding difference in \( K_u V/k_B T \) between LCP and RCP excitations from Eq. (5) is 1.1.

From the properties of FePt grains, we estimate the temperature difference to result in a change in \( K_u V/k_B T \) of 1.1. For a magnetic grain with 12 nm diameter, 10 nm height, and a magnetic anisotropy of \( K_u = 4.3 \times 10^7 \) ergs/cm\(^3\), we can estimate that room temperature \( K_u V/k_B T \) is ~1200. Since \( K_u V/k_B T \) goes to zero at \( T_C \sim 700 \) K, we can roughly estimate that \( K_u V/k_B T \) decreases on the order of 3 per K temperature change. This estimation suggests that there is only small difference in
temperature of ~1/3 K due to excitation of RCP and LCP that is consistent with the observed $P_1$ and $P_2$ values and with typical dichroism differences in magnetic metals.\textsuperscript{10} However, these estimates ignore any interactions between particles, any distributions in particle size or the specific dependence of temperature on time after excitation. Since the submission of this article, three recent papers have modeled the thermal origin difference in $P_1$ and $P_2$ in significant detail and qualitatively agree with the arguments given above.\textsuperscript{22,23,24}

We can further estimate how close to $T_C$ we would have to heat the sample to observe the statistical switching that we found. Using Eqs. (1) and (2) and assuming that the sample is heated for 1 ns, $K_u V/k_B T$ would need to be 7.6 for $P_1=0.0048$ and 8.7 for $P_2=0.0016$, suggesting that we are heating close to $T_C$. This observation can also explain, in part, the results in Fig. 4 where the demagnetization and optical reversal depends on the number of consecutive pulses. While one may think that with a repetition rate of 1 kHz that there is sufficient time to cool down to ambient temperature between pulses, there appears to be some accumulated heating. However, heating of only 1 K would be sufficient to change the switching probabilities since we are heating close to $T_C$. In the case of the FePt continuous film, the absorbed heat from the light can be dispersed quickly. Therefore, the film is not irreversibly damaged even at 190 mJ/cm\textsuperscript{2}. However, for the granular film, FePt grains are heated more effectively by the light exposure because of the thermal isolation of adjacent grains by the amorphous carbon segregant whose thermal conductivity is more than ten times lower than that of FePt. For laser exposure higher than 120 mJ/cm\textsuperscript{2}, results in irreversible
damage of the FePt-C granular film.

Since we do not have experimental results how the inverse Faraday field affects the switching process, we cannot conclude whether the AOS process is governed by only MCD. Note that, John et al.\textsuperscript{21} investigated experimentally and theoretically the AOS of FePt-C media. They reported that the magnetization switching in FePt grains is a stochastic process and multiple pulses are necessary to switch, which agrees with our results. Based on modeling, they concluded that the deterministic switching will be possible with both MCD and IFE. Ellis et al.\textsuperscript{22} concluded from modelling that IFE alone without MCD would require very high IFE fields and experimental results can be understood solely from MCD.

Here, we show the deterministic magnetization switching of the combination of circularly polarized light and modest external magnetic fields compared to HAMR. In currently developed so-called “small thermal spot HAMR”, the thermal spot is much smaller than the magnetic field spot. The magnetic field spot has a dimension of microns, while the heat spot is only a few tens of nanometers in diameter. Therefore, the bit transitions and the track width are defined by the thermal spot. If circularly polarized light could be used as the thermal spot, it acts on the same length scale as the thermal spot of current near field transducers (NFTs), but would require NFTs to produce circularly polarized light\textsuperscript{25}. In addition, the smaller magnetic field necessary for complete write may allow to push the writing point closer to the Curie point, which means generally a steeper anisotropy field (H\textsubscript{K}) versus temperature slope. Both of these effects should then increase the
effective magnetic field gradient when writing the transitions and also sharpen the track edge profile, allowing smaller tracks and sharper bit transitions since part of the magnetic reversal is now triggered by the small thermal spot and the writing point may be pushed closer towards Tc. Therefore, we can expect that the circularly polarized light can aid the writing in a HAMR-like recording process and lowers the external field required which is important for scaling of HAMR to higher areal densities.

V. CONCLUSION

In conclusion, we have shown that the optical magnetic switching for granular FePt films, designed for ultrahigh-density recording, by circularly polarized light is an accumulative effect of multiple optical pulses. This is qualitatively different from the AOS mechanism for GdFeCo, but closer to the behavior reported for Pt/Co/Pt structures.\textsuperscript{25} The observed AOS in FePt granular media can be described by a statistical model considering a small probability of switching magnetic grains for each light pulse and these probabilities depend on the helicity of the light. This results in a high degree of alignment of FePt grains \(\sim 75\%\), achieved only with multiple circularly polarized optical pulses. We further show that deterministic magnetization switching is achievable by the combination of circularly polarized light and modest external magnetic fields demonstrating that the circularly polarized light can aid the writing in a HAMR-like recording process. This study also suggests that the fully deterministic switching using only AOS for high-anisotropy nanostructures may require
more complex structures or application and control of an optical induced magnetic field.

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References


Figure captions,

**Figure 1** Schematic of the magnetization sensitive optical microscope combined with hall-cross measurement technique. The laser induced magnetization change is obtained by measuring the corresponding change in Hall voltage across the Hall cross arm via the anomalous Hall effect.

**Figure 2** Microstructure and magnetic properties of FePt-C and FePt films. (a) plan-view TEM bright field image. The corresponding nanobeam diffraction pattern and histogram of FePt grain size are shown in the insets, (b) a cross sectional TEM image and (c) magnetization curves of the FePt-C granular film. (d), (e) and (f) are the same as (a), (b) and (c), respectively, but for the corresponding FePt continuous film.

**Figure 3** Magnetization change observed from a FePt-C granular film by exposure to circular polarized light. (a) Magneto-optical image after slow sweeping of the LCP and RCP pulsed laser beam at a repetition rate of 1 kHz. The fluence is 35.7 mJ/cm². The sample was initially demagnetized. Note that we show a subtracted image obtained from before and after applying the laser exposure. (b) same as (a), but the sample was initially remanence state after applying the magnetic field of 7 T. The fluence is 48.1 mJ/cm². (c) AHE curve for the FePt-C granular film. The additional data points at zero field correspond to the amount of magnetization switched by sweeping the right and left circular polarized light in the Hall cross in a similar way as shown in (a) and (b). (d) Normalized Hall resistance after applying circular and linear polarized light as a function of the integrated number of pulses. Red, blue and black dots correspond to the normalized Hall resistance after applying the RCP, LCP and linear polarized light. The initial state is the spin-up state in all FePt grains. The dotted lines show the fit obtained using the accumulative magnetic switching model described in the main text. The fluence was 101.9 mJ/cm². (e) Normalized Hall resistance after illumination with RCP, LCP and linear polarized light. The initial state is the spin-down state in all FePt grains.

**Figure 4** Normalized hall-resistance that corresponds to the net magnetization in the film is plotted against the sequence of pulses used to pump. (a) shows the curves for various sequences of number of RCP pulses varying from 20-160 pulses with a fluence of 79.6 mJ/cm². (b) same as (a) but for a fluence of 107.5 mJ/cm². The inset shows the same as (b) for the sequence of 1000 pulses.

**Figure 5** Normalized Hall resistance for FePt continuous (red) and FePt-C granular (blue) films versus fluence. The initial state was spin-up in FePt grains. The number of pulses was 80 for both samples. RCP light was used.
Figure 6: Schematic of the film, (center) magnetization curves and (bottom) microstructure of FePt-C ECC media are shown for various thickness of the semi-hard FePt layer of (a) 0 nm, (b) 5 nm, (c) 10 nm and (d) 15 nm.5

Figure 7: Normalized Hall resistance measured after the laser beam exposure in the FePt-C ECC media is plotted as a function of the thickness of FePt semi-hard layer. The laser fluence was 24.5 mJ/cm². Inset shows how the normalized Hall resistance toggles between the negative and positive values via zero, when the exposed laser beam helicity is changed between left and right circular polarization via linear.

Figure 8 (a) Normalized Hall resistance is plotted as a function of the number of sequence N, for the case of linearly polarized light under the influence of an external magnetic field of ±0.051 T. Note the change of magnetic field direction after the exposure of N=5. (b) same as (a), but with a higher external magnetic field of ±0.2 T. The blue curve shows the data for the case when the initial magnetic state is along spin-down direction and the red one for spin-up direction. The pulse number in each sequence is 80. The light fluence was 107.5 mJ/cm². (c) same as (b), but for the cases of left and right circularly polarized light sequences. The data is shown for the both cases of initial magnetization state along spin-up (red) and spin-down (blue).
Figure 5

Normalized Hall resistance vs. fluence (mJ/cm²)

- Continuous MgO/FePt(10)/C(10)
- Granular MgO/FePt-30% C(10)/C(10)
Figure 6